



MRF8372GR2 Information



For Reference Only

Part Number MRF8372GR2

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF

Description TRANS NPN 16V 200MA SO8 **Package** 8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MRF8372GR2 Specifications

M C , D , N 1	MDE0272CD2
Manufacturer Part Number	MRF8372GR2
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	8-SOIC (0.154", 3.90mm Width)
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	16V
Frequency - Transition	870MHz
Noise Figure (dB Typ @ f)	-
Gain	8dB ~ 9.5dB
Power - Max	2.2W
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 50mA, 5V
Current - Collector (Ic) (Max)	200mA
Operating Temperature	-
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SO
	Report errors?

MRF8372GR2 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MRF8372GR2 Payment Methods



















MRF8372GR2 Shipping Methods













If you have any question about MRF8372GR2, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com